No.634D	DSA-26
SANYO	Diffused Junction Type Silicon Diode
	2.6A Power Rectifier

## Features

- · Plastic molded type
- · Iligh reliability attained by glass passivation
- $\cdot$  Peak reverse voltage  $\,V_{RM}\!=\!-100\,to-400V$   $\cdot$  Average rectified current  $\,I_{O}\!=\!2.6A$

Absolute Maximum Ratings at Ta = 25°C		DSA26B	DSA26C	DSA26E	unit	
Peak Reverse Voltage	$V_{RM}$		-100	-200	-400	v
Average Rectified Current	IO	$Ta = 40^{\circ}C$	$\rightarrow$	$\rightarrow$	2.6	А
		$Ta = 40^{\circ}C$ , with 2 Cu fin $c$	of $20 \times 20 \times 1$ mm <sup>3</sup>	$\rightarrow$	3.5	Α
Surge Forward Current	I <sub>FSM</sub>	50Hz sine wave,1 cycle	$\rightarrow$	$\rightarrow$	120	Α
Junction Temperature	Tj		$\rightarrow$	$\rightarrow$	150	°C
Storage Temperature	Tstg		<b>→</b>	- 3	0 to +150	°C
Electrical Characteristics at Ta = 25°C			min ty	p max	unit	
Forward Voltage	$V_F$	$I_{F} = 2.6A$		-	1.05	V
Reverse Current	I <sub>R</sub>	$V_R$ : At each $V_{RM}$			-10.0	μÅ





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D218TA,TS No.634-1/2



third parties.

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